



## Research and Application of Wide Band Gap Semiconductors

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### Message from the Guest Editors

Dear Colleagues,

The emerging generation of power semiconductor devices based on wide bandgap (WBG) semiconductors is revolutionizing the power device market. Improved material quality and painstaking R&D efforts have enabled superior device performances for 4H-SiC MOSFETs and GaN HEMTs when compared to equivalent Si-based solutions.

However, the success of future generation devices relies upon addressing several scientific challenges.

1. Optimization of material growth towards low defect density substrates and thick epi layers.
2. Comprehensive understanding of the role of defects in the electrical and thermal performance of final devices.

This Special Issue aims to highlight and collect the latest advancements in device fabrication, material growth, device electro-thermal modeling and simulations, lateral and vertical novel device configurations, reliability tests and measurements, as well as converter- and system-related solutions for both WBG and UWBG devices.





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## Editor-in-Chief

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## Message from the Editor-in-Chief

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